# NSN 5961-01-036-6331

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#### Inclosure Material:

Metal

#### **Overall Length:**

Between 0.190 inches and 0.315 inches

# **Overall Diameter:**

0.875 inches

# **Mounting Facility Quantity:**

2

## Internal Configuration:

Junction contact

# Electrode Internally-electrically Connected To Case:

Collector

## **Mounting Method:**

Unthreaded hole

## Features Provided:

Hermetically sealed case

#### Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

80.0 breakdown voltage, collector-to-emitter, base open and 90.0 collector to base voltage/static/emitter open and 5.0 breakdown voltage,

emitter-to-base, collector open

# **Current Rating Per Characteristic:**

30.00 amperes source cutoff current

## Power Rating Per Characteristic:

150.0 watts small-signal input power, common-collector preset

#### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Mtg heat sink included; junction pattern arrangement: npn

#### **Terminal Type And Quantity:**

2 uninsulated wire lead and 1 case

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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